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## BIB DATA SHEET

CONFIRMATION NO. 5456

<b>SERIAL NUMBER</b> 10/597,066	<b>FILING or 371(c) DATE</b> 07/10/2006 <b>RULE</b>	<b>CLASS</b> 257	<b>GROUP ART UNIT</b> 2813	<b>ATTORNEY DOCKET NO.</b> FIS920030342US1	
<b>APPLICANTS</b> Huajie Chen, Danbury, CT; Stephen W. Bedell, Wappingers Falls, NY; Devendra K. Sadana, Pleasantville, NY; Dan M. Mocuta, LaGrangeville, NY; <b>** CONTINUING DATA *****</b> This application is a 371 of PCT/US04/01555 01/16/2004 <b>** FOREIGN APPLICATIONS *****</b> <b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 02/26/2007					
Foreign Priority claimed <input type="checkbox"/> Yes <input checked="" type="checkbox"/> No 35 USC 119(a-d) conditions met <input type="checkbox"/> Yes <input checked="" type="checkbox"/> No Verified and /LAURA MARY Acknowledged MENZ/ Examiner's Signature	<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> CT	<b>SHEETS DRAWINGS</b> 10	<b>TOTAL CLAIMS</b> 15	<b>INDEPENDENT CLAIMS</b> 1
<b>ADDRESS</b> INTERNATIONAL BUSINESS MACHINES CORPORATION DEPT. 18G BLDG. 300-482 2070 ROUTE 52 HOPEWELL JUNCTION, NY 12533 UNITED STATES					
<b>TITLE</b> Method of forming thin sgoi wafers with high relaxation and low stacking fault defect density					
<b>FILING FEE RECEIVED</b> 300	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		